



1H1G thru 1H8G

Glass Passivated High Efficient Rectifiers
Reverse Voltage 50 to 1000 Volts Forward Current 1.0 Ampere

Features

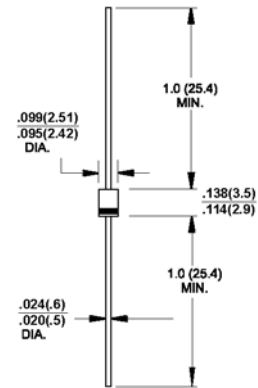
- ◆ Low forward voltage drop
- ◆ High current capability
- ◆ High reliability
- ◆ High surge current capability



R-1

Mechanical Data

- ◆ Case: Molded plastic R-1
- ◆ Epoxy: UL 94V-O rate flame retardant
- ◆ Lead: Axial leads, solderable per MIL-STD-202, Method 208 guaranteed
- ◆ Polarity: Color band denotes cathode end
- ◆ High temperature soldering guaranteed:
250°C/10 seconds .375" (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ◆ Mounting position: Any
- ◆ Weight: 0.007 ounce, 0.20 gram



Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

| Parameter | Symbols | 1H1G | 1H2G | 1H3G | 1H4G | 1H5G | 1H6G | 1H7G | 1H8G | Units | |
|---|-----------|-------------|------|------|------|------|------|------|------|------------------|----|
| Maximum repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 200 | 300 | 400 | 600 | 800 | 1000 | Volts | |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 140 | 210 | 280 | 420 | 560 | 700 | Volts | |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 200 | 300 | 400 | 600 | 800 | 1000 | Volts | |
| Maximum average forward rectified current .375" (9.5mm) lead length @ $T_A=55^\circ\text{C}$ | I_{AV} | 1.0 | | | | | | | | Amp | |
| Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I_{FSM} | 30.0 | | | | | | | | Amps | |
| Maximum instantaneous forward voltage @ 1.0A | V_F | 1.0 | | | 1.3 | | 1.7 | | | Volts | |
| Maximum DC reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=125^\circ\text{C}$ | I_R | 5.0 | | | | 100 | | | | μA | |
| Maximum reverse recovery time (Note 1) | t_{rr} | 50 | | | | | 75 | | | | nS |
| Typical junction capacitance (Note 2) | C_J | 20 | | | | | 15 | | | | pF |
| Operating junction temperature range | T_J | -55 to +150 | | | | | | | | $^\circ\text{C}$ | |
| Storage temperature range | T_{STG} | -55 to +150 | | | | | | | | $^\circ\text{C}$ | |

- Notes:**
1. Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$
 2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

RATINGS AND CHARACTERISTIC CURVES

FIG.1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

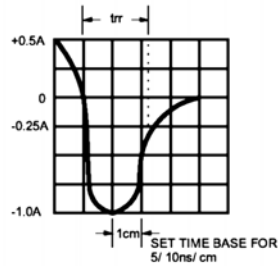
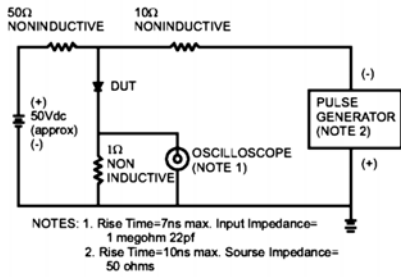


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE

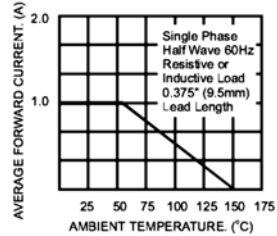


FIG.3- TYPICAL REVERSE CHARACTERISTICS

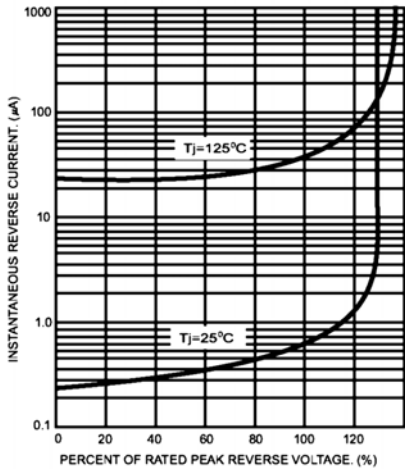


FIG.4- TYPICAL FORWARD CHARACTERISTICS

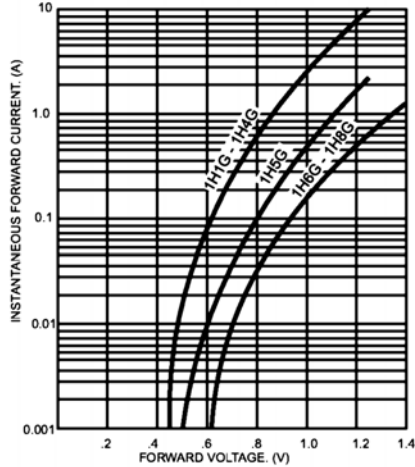


FIG.5- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

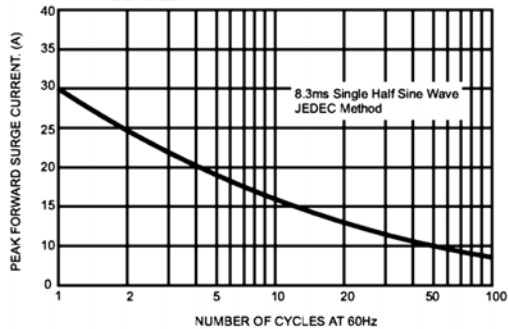


FIG.6- TYPICAL JUNCTION CAPACITANCE

